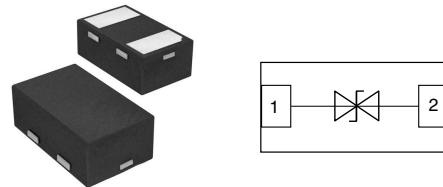


## ESD Protection Diode in DFN1006

### Features

- 160Watts peak pulse power ( $T_p = 8/20\mu s$ )
- DFN1006 package
- Bidirectional configurations
- Low clamping voltage
- Low leakage current
- Solid-state silicon-avalanche technology
- Protection one data/power line to:  
IEC 61000-4-2 ±30kV contact ±30kV air  
IEC 61000-4-4 (EFT) 40A (5/50ns)  
IEC 61000-4-5 (Lightning) 18A (8/20μs)



### Mechanical Data

- **Case:** DFN1006 (plastic package).  
Lead free; RoHS compliant; Halogen free
- **Molding Compound Flammability Rating:**  
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:  
260 °C/10 sec. at terminals

### Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

### Absolute Maximum Ratings

Ratings at 25 °C, ambient temperature unless otherwise specified

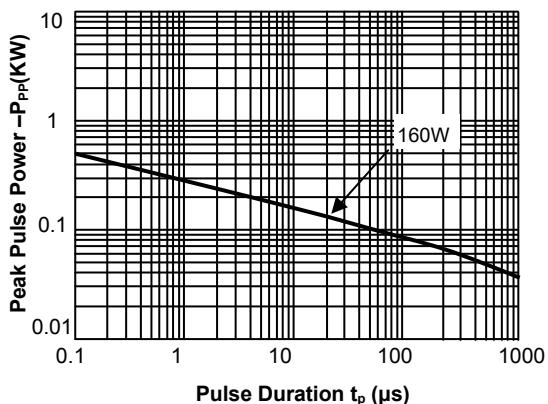
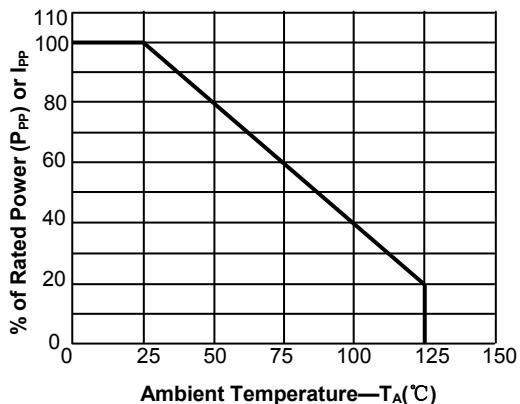
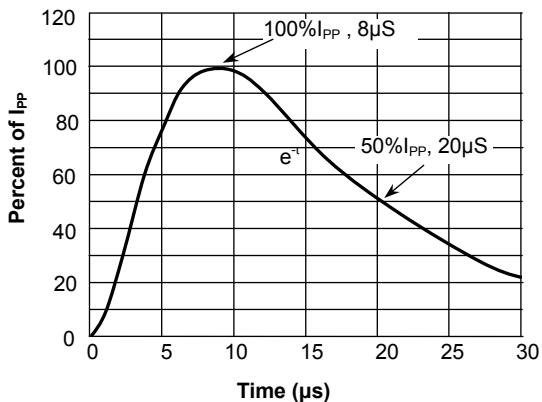
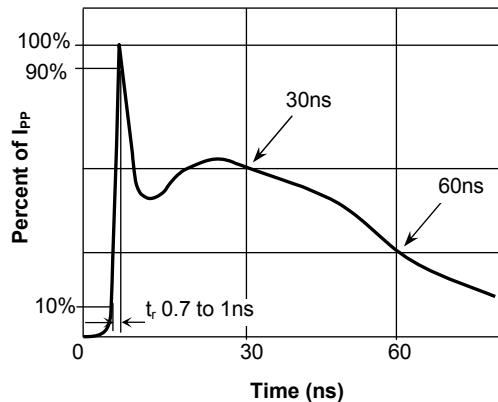
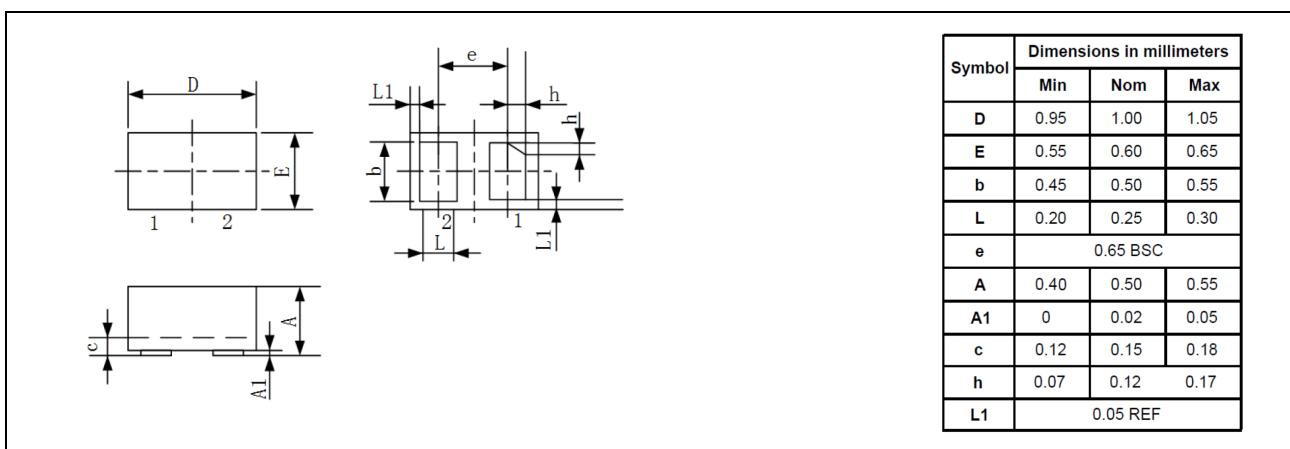
Parameter	Symbol	Value	Unit
Peak Pulse Power ( $T_p=8/20\mu s$ )	$P_{PP}$	160	W
ESD contact/air discharge (IEC-61000-4-2)	$V_{ESD}$	30/30	kV
Peak Pulse Current ( $T_p = 8/20\mu s$ )	$I_{PP}$	18	A
Junction Temperature	$T_J$	-55 to +125	°C
Storage temperature	$T_{STG}$	-55 to +125	°C

### Electrical Characteristics

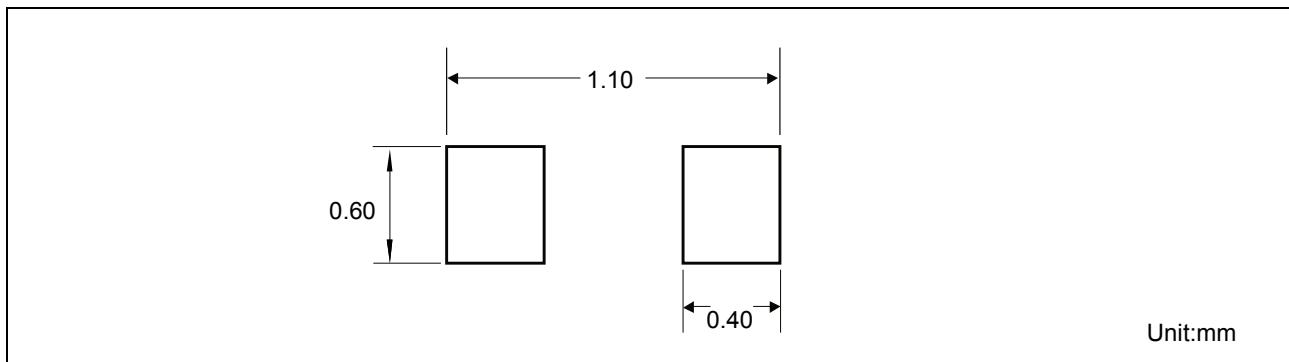
( $T_A = 25$  °C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	$V_{RWM}$				3.3	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1mA$	4.0			V
Reverse Leakage Current	$I_R$	$V_{RWM}=3.3V, T=25^\circ C$			1	µA
Clamping Voltage	$V_{CL}$	$I_{PP}=16A, t_p=100ns$		8		V
Clamping Voltage	$V_C$	$I_{PP}=5A, t_p=8/20\mu s$			6	V
Clamping Voltage		$I_{PP}=18A, t_p=8/20\mu s$		9		V
Dynamic resistance	$R_{DYN}$			0.2		Ω
Junction Capacitance	$C_j$	$V_R = 0V, f = 1MHz$		30		pF

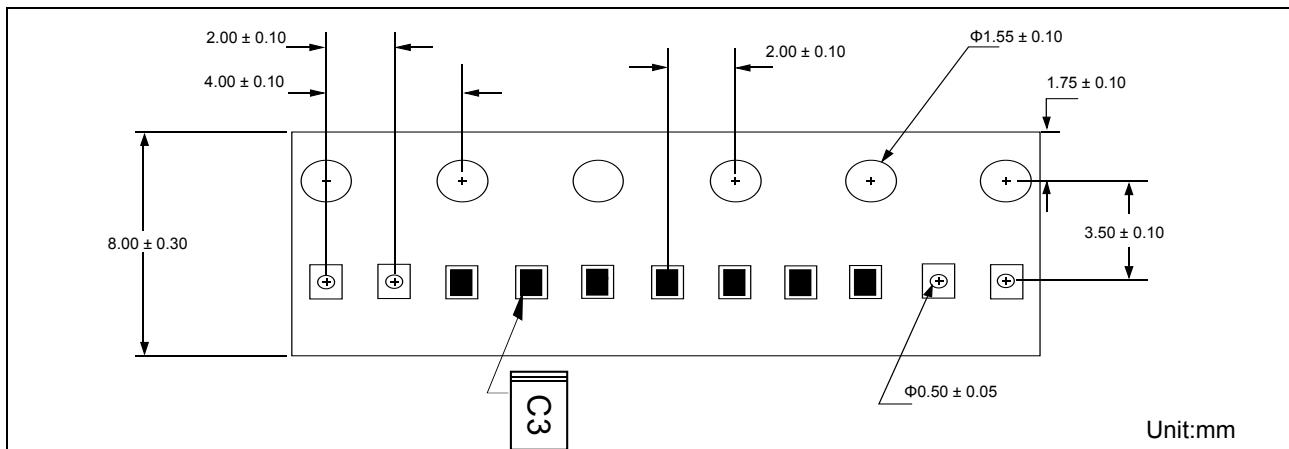
**Typical Characteristics** ( $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified)

**Fig.1 Peak Pulse Power Rating Curve**

**Fig.2 Pulse Derating Curve**

**Fig.3 Pulse Waveform-8/20μs**

**Fig.4 Pulse Waveform-ESD(IEC61000-4-2)**

**Package Dimensions**


### Pad Dimensions



### Tape and Reel Specification



### Marking



### Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
TESD1006NC3V3BH	DFN1006	Tape and reel	10000pcs / reel	EIA STD RS-481